

Peak Emission Wavelength: 560nm, 585nm, 635nm, 660nm

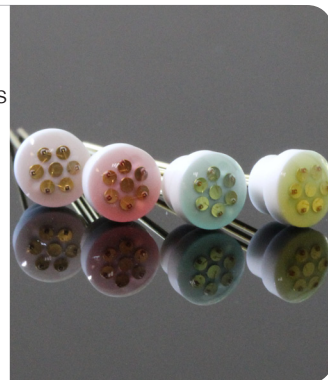
The MT106F-xxx is a high reliability multi-chip emitter designed for applications requiring various wavelengths or more than one die in a single package. These devices can be custom sorted for specific power output.

FEATURES

- > High Luminance / High Reliability
- > Wide Radiation Pattern / White Ceramic Base
- > Low Power Consumption
- > Alternate Electrical Configurations

APPLICATIONS

- > Currency Validation
- > Medical / Biofluorescence
- > General Indication
- > Push Button Backlight



Absolute Maximum Ratings (Ta=25°C)

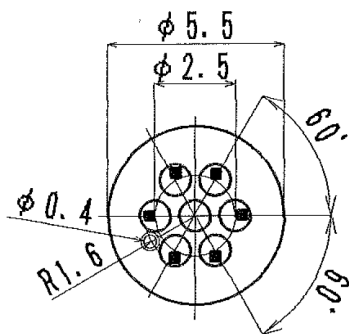


ITEMS	SYMBOL	RATINGS	UNIT
Forward Current	IF	15	mA
Reverse Voltage	VR	24	V
Power Dissipation	PD	240	mW
Operating Temperature Range	Topr	-20 ~ +60	°C
Storage Temperature Range	Tstg	-30 ~ +100	°C
Lead Soldering Temperature*1	Tls	260	°C

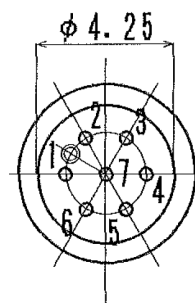
*1: Time 5 Sec max, Position: Up to 3mm from the body.

Electrical & Optical Characteristics (Ta = 25°C)

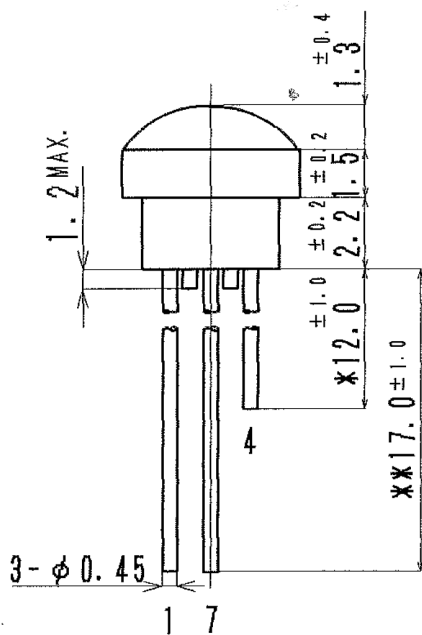
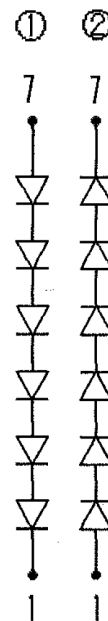
PART NO.	IV (typ) @IF=10mA	VF(typ) @IF=10mA	VF(max) @IF=10mA	IR(max) @VR=24V	λp(typ) @IF=10mA	Δλ(typ) @IF=10mA	Circuit No
MT106F-UG	50mcd	12.0V	14.4V	100μA	565nm	30nm	(1)
MT106F-YL	20mcd	11.5V	13.8V	100μA	585nm	30nm	(1)
MT106F-HR	25mcd	11.0V	13.2V	100μA	635nm	35nm	(1)
MT106F-URD	100mcd	10.5V	12.6V	100μA	660nm	20nm	(2)



■ LED Chip



No. 2, 3, 5, 6 PIN CUT
** No. 1, 7
* No. 4



Unit: mm, Tolerance: ± 0.2

The information contained herein is subject to change without notice.

2013-06-05